

L-53SEC-E HYPE ORANGE

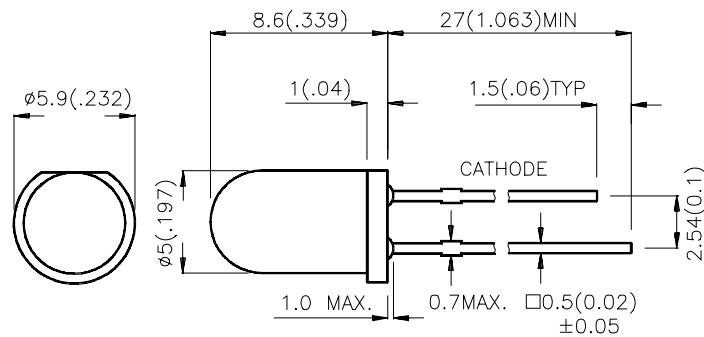
### Features

- LOWPOWERCONSUMPTION.
- POPULAR T-1 3/4 DIAMETER PACKAGE.
- GENERALPURPOSELEADS.
- RELIABLEANDRUGGED.
- LONGLIFE - SOLID STATEREIABILITY.

### Description

The Hyper Orange source color devices are made with DH InGaAlP on GaAs substrate Light Emitting Diode.

### Package Dimensions



#### Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is  $\pm 0.25(0.01)$  unless otherwise noted.
3. Lead spacing is measured where the lead emerge package.
4. Specifications are subject to change without notice.

## Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) @ 20 mA		Viewing Angle
			Min.	Typ.	2θ1/2
L-53SEC-E	HYPER ORANGE (InGaAlP)	WATER CLEAR	1500	5000	30°

Note:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

## Electrical / Optical Characteristics at T<sub>A</sub>=25°C

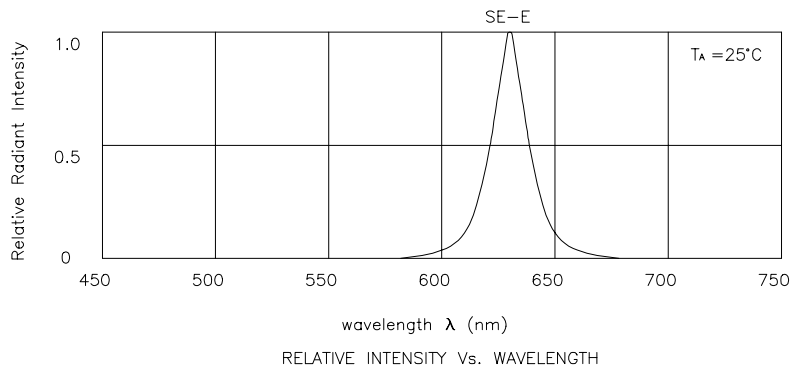
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ <sub>peak</sub>	Peak Wavelength	Hyper Orange	630		nm	I <sub>F</sub> =20mA
λ <sub>D</sub>	Dominate Wavelength	Hyper Orange	621		nm	I <sub>F</sub> =20mA
Δλ <sub>1/2</sub>	Spectral Line Half-width	Hyper Orange	20		nm	I <sub>F</sub> =20mA
C	Capacitance	Hyper Orange	25		pF	V <sub>F</sub> =0V;f=1MHz
V <sub>F</sub>	Forward Voltage	Hyper Orange	2.0	2.5	V	I <sub>F</sub> =20mA
I <sub>R</sub>	Reverse Current	Hyper Orange		10	μA	V <sub>R</sub> = 5V

## Absolute Maximum Ratings at T<sub>A</sub>=25°C

Parameter	Hyper Orange	Units
Power dissipation	150	mW
DC Forward Current	30	mA
Peak Forward Current [1]	195	mA
Reverse Voltage	5	V
Operating/Storage Temperature	-40°C To +85°C	
Lead Solder Temperature [2]	260°C For 5 Seconds	

Notes:

- 1/10 Duty Cycle, 0.1ms Pulse Width.
- 2mm below package base.



## Hyper Orange

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